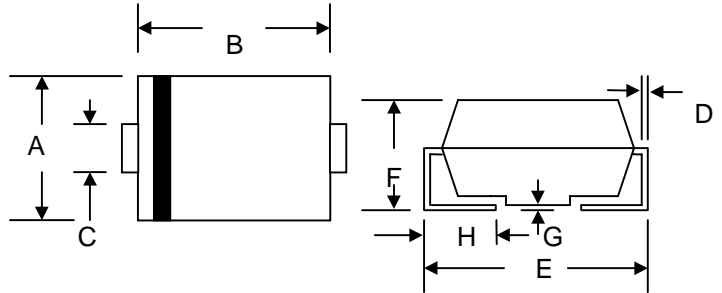


Features

- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop
- Surge Overload Rating to 30A Peak
- Low Power Loss
- Built-in Strain Relief
- Plastic Case Material has UL Flammability Classification Rating 94V-O



Mechanical Data

- Case: Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.064 grams (approx.)
- **Lead Free: For RoHS / Lead Free Version**

SMA/DO-214AC		
Dim	Min	Max
A	2.50	2.90
B	4.00	4.60
C	1.40	1.60
D	0.152	0.305
E	4.80	5.28
F	2.00	2.44
G	0.051	0.203
H	0.76	1.52
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbo	GS1A	GS1B	GS1D	GS1G	GS1J	GS1K	GS1M	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Working Peak Reverse Voltage	V_{RWM}								
DC Blocking Voltage	V_R								
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Rectified Output Current @ $T_L = 100^\circ\text{C}$	I_O	1.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30							A
Forward Voltage @ $I_F = 1.0\text{A}$	V_{FM}	1.0							V
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 125^\circ\text{C}$	I_{RM}	2.0 200							μA
Typical Junction Capacitance (Note 1)	C_j	15							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JL}$	30							K/W
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150							$^\circ\text{C}$

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC.
2. Mounted on P.C. Board with 8.0mm² land area.

Zibo Seno Electronic Engineering Co., Ltd.



GS1A-GS1M  

